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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTORS

# 2SK2499, 2SK2499-Z

## SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### **DESCRIPTION**

The 2SK2499 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

#### **FEATURES**

· Low On-Resistance

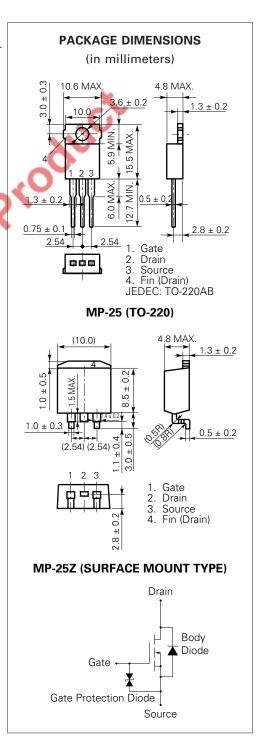
 $R_{DS(on)1} = 9 \text{ m}\Omega \text{ (VGS} = 10 \text{ V, ID} = 25 \text{ A)}$   $R_{DS(on)2} = 14 \text{ m}\Omega \text{ (VGS} = 4 \text{ V, ID} = 25 \text{ A)}$ 

- Low Ciss Ciss = 3 400 pF TYP.
- · High Avalanche Capability.
- · Built-in G-S Protection Diode

### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	ID(DC)	±50	Α
Drain Current (pulse)*	ID(puls	±200	Α
Total Power Dissipation (Tc = 25 °C)	P <sub>T1</sub>	75	W
Total Power Dissipation (TA = 25 °C)	P <sub>T2</sub>	1.5	W
Channel Temperature	$T_ch$	150	°C
Storage Temperature	$T_{stg}$	-55 to +150	°C
Single Avalanche Current**	las	50	Α
Single Avalanche Energy**	Eas	250	mJ

- \* PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %
- \*\* Starting T<sub>ch</sub> = 25 °C, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20 V  $\rightarrow$  0



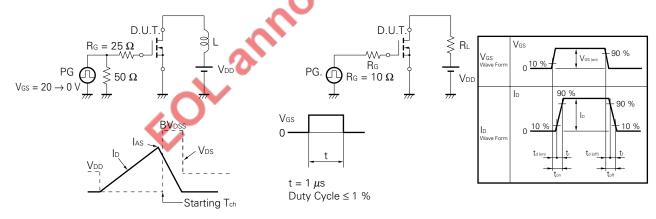


### **ELECTRICAL CHARACTERISTICS (TA = 25 °C)**

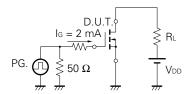
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-State Resistance	RDS(on)1		7.3	9.0	mΩ	Vgs = 10 V, ID = 25 A
	RDS(on)2		11	14	mΩ	Vgs = 4 V, ID = 25 A
Gate to Source Cutoff Voltage	V <sub>GS(off)</sub>	1.0	1.5	2.0	V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA
Forward Transfer Admittance	yfs	20	58		S	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 25 A
Drain Leakage Current	IDSS			10	μΑ	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0
Gate to Source Leakage Current	Igss			±10	μΑ	$V_{GS} = \pm 20 \text{ V, } V_{DS} = 0$
Input Capacitance	Ciss		3 400		pF	V <sub>DS</sub> = 10 V
Output Capacitance	Coss		1 600		pF	V <sub>GS</sub> = 0
Reverse Transfer Capacitance	Crss		770		pF	f = 1 MHz
Turn-On Delay Time	td(on)		55		ns	ID = 25 A
Rise Time	tr		360		ns	V <sub>GS(on)</sub> = 10 V
Turn-Off Delay Time	td(off)		480		ns	V <sub>DD</sub> = 30 V
Fall Time	tf		360		ns	$R_G = 10 \Omega$
Total Gate Charge	Qg		152		nC	lo = 50 A
Gate to Source Charge	Qgs		11		nC	V <sub>DD</sub> = 48 V
Gate to Drain Charge	Q <sub>GD</sub>		60		nC	V <sub>GS</sub> = 10 V
Body Diode Forward Voltage	V <sub>F(S-D)</sub>		0.92	Y	V	IF = 50 A, VGS = 0
Reverse Recovery Time	trr		105	2	ns	IF = 50 A, VGS = 0
Reverse Recovery Charge	Qrr		265		nC	$di/dt = 100 A/\mu s$

### Test Circuit 1 Avalanche Capability

# **Test Circuit 2 Switching Time**



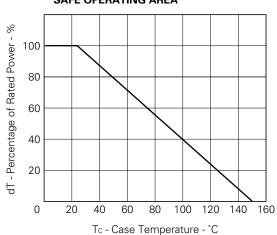
### **Test Circuit 3 Gate Charge**



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

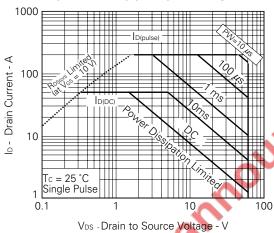
### TYPICAL CHARACTERISTICS (TA = 25 °C)





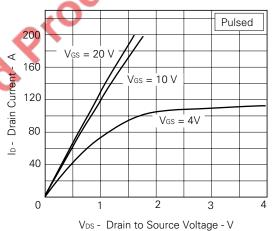
# TOTAL POWER DISSIPATION vs. CASE TEMPERATURE PT - Total Power Dissipation - W

#### FORWARD BIAS SAFE OPERATING AREA

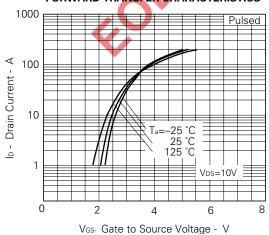


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

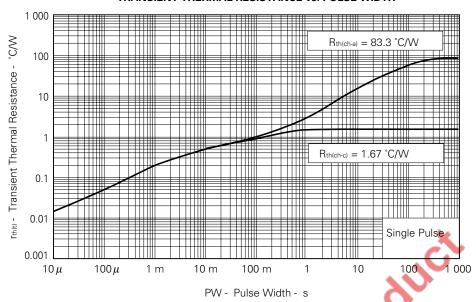
Tc - Case Temperature - °C



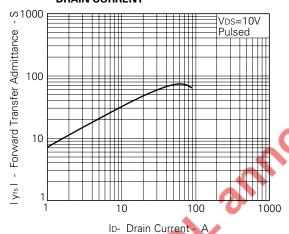
### FORWARD TRANSFER CHARACTERISTICS



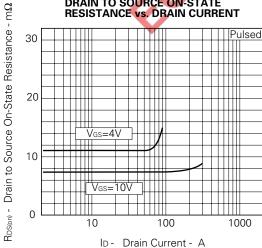
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



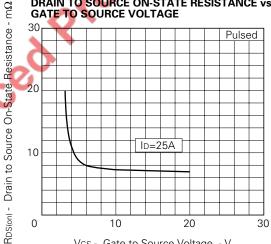
#### FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

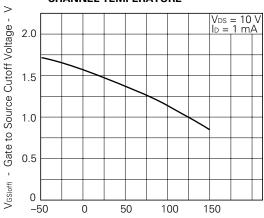


# DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

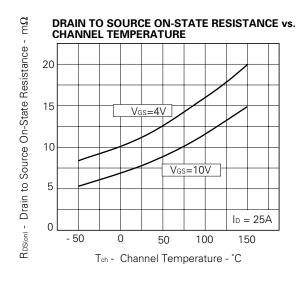


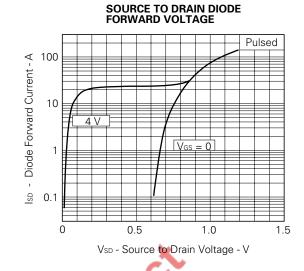
### Vgs - Gate to Source Voltage - V

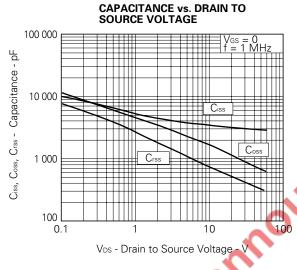
# GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

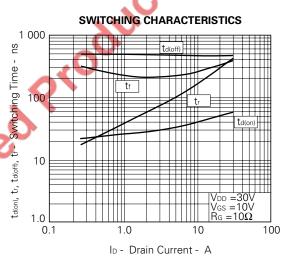


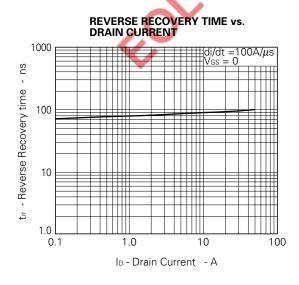
Tch - Channel Temperature - °C

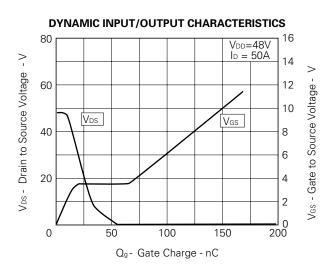






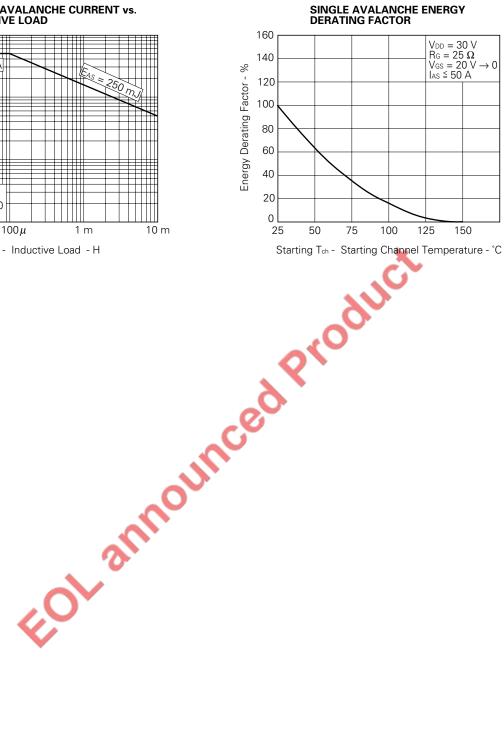






# SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD 100 las - Single Avalanche Current - A Ias = 50 A 10 1.0 $V_{DD} = 30 \text{ V}$ $V_{GS} = 20 \text{ V} \rightarrow 0$ $0.1 \frac{R_G = 25 \Omega}{\Omega}$ 10 μ $100\mu$

L - Inductive Load - H



Starting Tch - Starting Channel Temperature - °C

### **REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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